

### SSCN114EGS6

### **NPN Type Digital Transistor (built-in resistors)**

#### Features

vcc	VIN	Ю	R1	R2/R1 Typ.
50V	-10~+40V	50mA	10kΩ	1.0

#### Description

Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).

The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects. Only the on/off conditions need to be set for operation, making the device design easy.

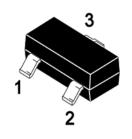
### Applications

- Amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance

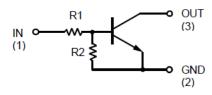
### Ordering Information

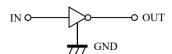
Device	Package	Shipping
SSCN114EGS6	SOT-23	3000/Reel

### Pin configuration

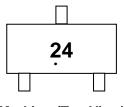


**SOT-23** 





**Circuit Diagram** 



**Marking (Top View)** 



# SSCN114EGS6

# ightharpoonup Absolute Maximum Ratings(T<sub>A</sub>=25°C unless otherwise noted)

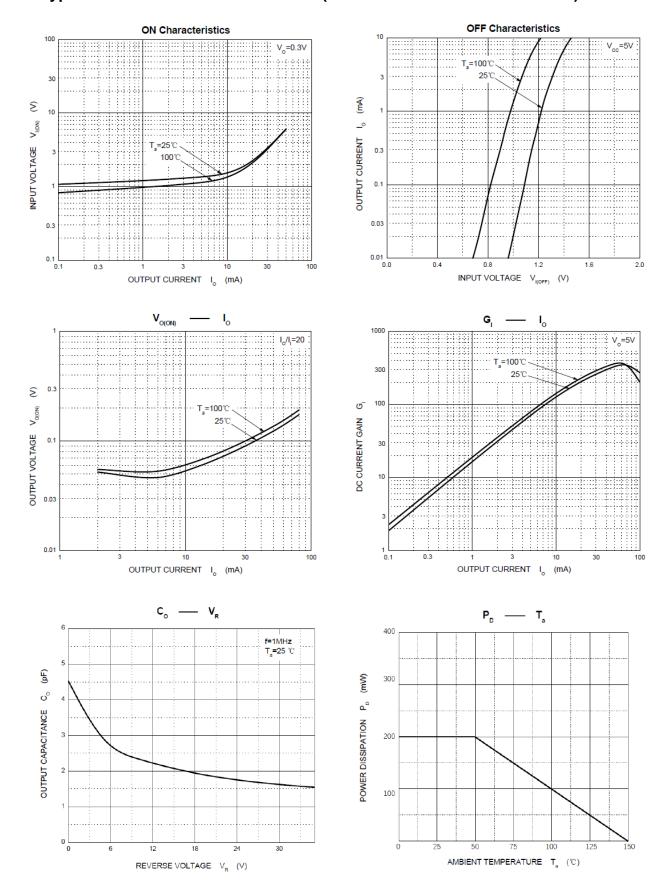
Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	50	V
Input Voltage	V <sub>CN</sub>	-10 to +40	V
Output current	lo	50	mA
Peak Collector Current	Ісм	100	mA
Power Dissipation	P <sub>D</sub>	200	mW
Junction Temperature	TJ	-55 to 150	$^{\circ}\!\mathbb{C}$
Storage Temperature	T <sub>STG</sub>	-55 to 150	$^{\circ}\!\mathbb{C}$

# $\succ$ Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Input Voltage	$V_{I(off)}$	$V_{CC} = 5V, I_{O} = 0.1 \text{mA}$	0.5			V
Input Voltage	$V_{I(on)}$	$V_{CC} = 0.3V$ , $I_{O} = 10mA$			3	V
Output Voltage	V <sub>O(on)</sub>	I <sub>O</sub> /I <sub>I</sub> = 10mA/0.5mA			0.3	V
Input Current	l <sub>l</sub>	V <sub>I</sub> = 5V			0.88	mA
Output Current	I <sub>O(off)</sub>	Vcc = 50V, Vı = 0V			0.5	uA
DC Current Gain	G <sub>1</sub>	$V_0 = 5V$ , $I_0 = 5mA$	30			
Input Resistance	R <sub>1</sub>		7	10	13	ΚΩ
Resistance Ration	R <sub>2</sub> /R <sub>1</sub>		0.8	1.0	1.2	
Transition Frequency	f⊤	Vo=10V,Io=5mA,f=100MHz		250		MHz



### > Typical Performance Characteristics (T<sub>A</sub>=25℃ unless otherwise noted)

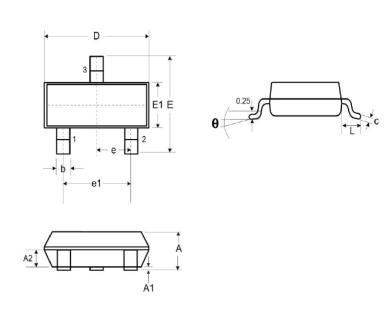




# Package Information

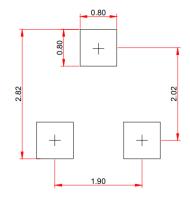
### Mechanical Data

### **SOT-23**



DIM	Millimeters				
DIM	Min.	Тур.	Max.		
Α	0.89	-	1.12		
<b>A</b> 1	0.01	-	0.10		
A2	0.88	0.95	1.02		
b	0.30	-	0.51		
С	0.08	-	0.18		
D	2.80	2.90	3.04		
E	2.10	2.37	2.64		
E1	1.20	1.30	1.40		
е	0.95				
e1		1.90			
L	0.40	0.50	0.60		
L1	0.55				
N	3				
θ	0°	-	8°		

### Recommended Pad outline





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